

Vishay Siliconix

N-Channel Reduced Q_g , Fast Switching MOSFET

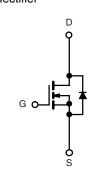
PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
30	0.008 at V _{GS} = 10 V	16			
	0.011 at V _{GS} = 4.5 V	15			

FEATURES

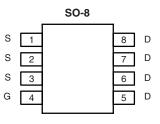
- Halogen-free According to IEC 61249-2-21
 Available
- TrenchFET[®] Power MOSFETs
- PWM Optimized for High Efficiency
- 100 % Rg Tested

APPLICATIONS

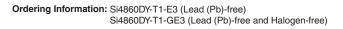
- Buck Converter
 - High Side
 - Low Side
- Synchronous Rectifier
 Secondary Rectifier



N-Channel MOSFET



Top View



ABSOLUTE MAXIMUM RATINGS	A = 25 °C, unles	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20			
	T _A = 25 °C	- I _D	16	11		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		13	8		
Pulsed Drain Current		I _{DM}	± 50		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	3.0	1.40		
	T _A = 25 °C	– P _D	3.5	1.6	W	
Maximum Power Dissipation ^a	T _A = 70 °C		2.2	1.0		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	29	35	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		67	80	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



HALOGEN

Available

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MOSFET SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.0			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
Zero Gate Voltage Drain Current	1	$V_{DS} = 24 V, V_{GS} = 0 V$			1			
	IDSS	V_{DS} = 24 V, V_{GS} = 0 V, T_{J} = 70 °C			5	μA		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			А		
Drain-Source On-State Resistance ^a	D	V _{GS} = 10 V, I _D = 16 A		0.0066	0.008	0		
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 15 A		0.0090	0.011	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 16 A		60		S		
Diode Forward Voltage ^a	V _{SD}	I _S = 3 A, V _{GS} = 0 V		0.70	1.1	V		
Dynamic ^b								
Total Gate Charge	Qg			13	18	nC		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 16 A		5				
Gate-Drain Charge	Q _{gd}			4.0				
Gate Resistance	Rg		1.0	1.7	2.9	Ω		
Turn-On Delay Time	t _{d(on)}			18	27			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		12	18			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		46	70	ns		
Fall Time	t _f			19	30			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3 A, dl/dt = 100 A/μs		40	70			

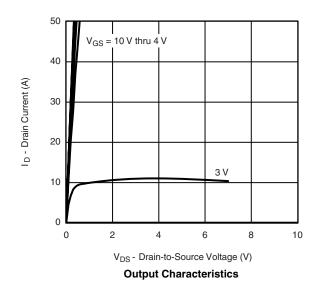
Notes:

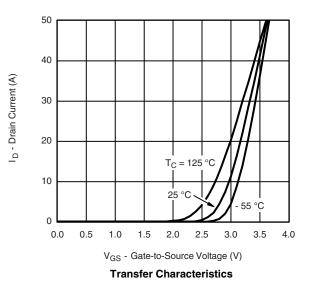
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





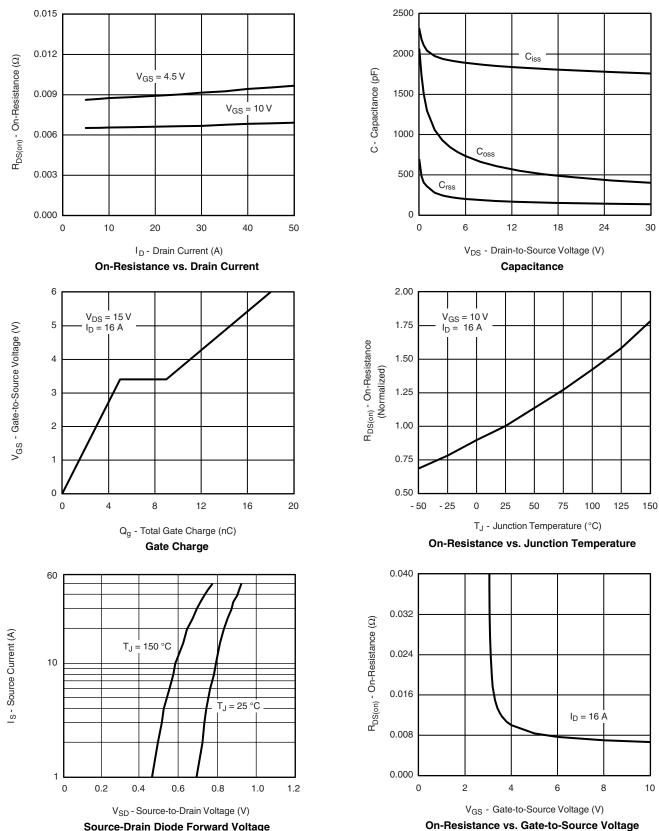
VISHA

Si4860DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

VISHAY

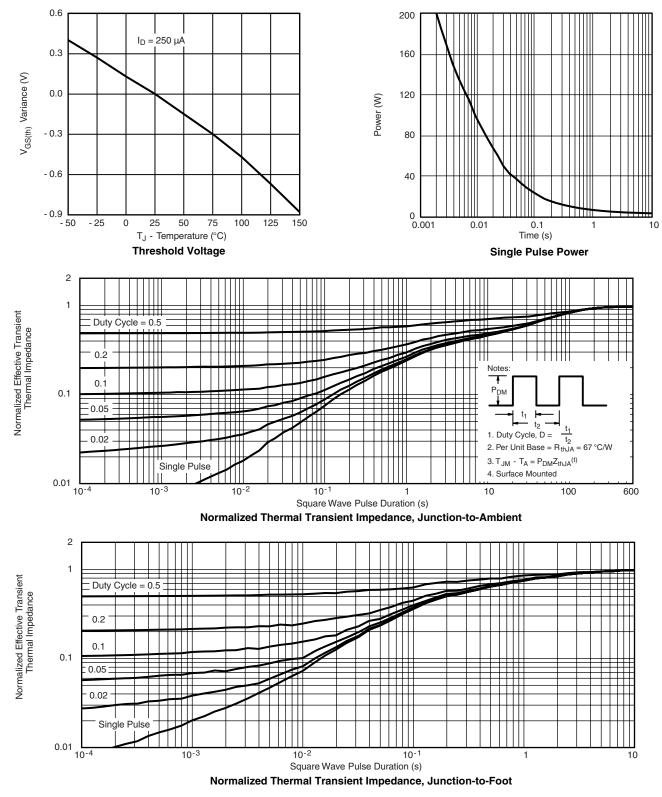


Source-Drain Diode Forward Voltage

Document Number: 71752 S0-0221-Rev. D, 09-Feb-09

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VISHA



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